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EDITORIAL CONTACT:

Rodd Novak, Director Product Marketing
(858) 731-2864

Cindy Trotto, PR/MarCom
(602) 750-7203

Reader/Literature Inquiries:

Richardson Electronics
1-800-737-6937

FOR IMMEDIATE RELEASE

OKI Electric Completes Transfer of Peregrine Semiconductor UTSi[®] Silicon-on-Sapphire Technology

San Diego, CALIFORNIA, April 27, 2004 -- Peregrine Semiconductor Corporation, a leading supplier of mixed-signal and RF CMOS communications ICs, today announced that, under a broad licensing agreement with OKI Electric Industry Co., Ltd. (TSE:6703), its 0.5 um UTSi[®] Silicon-on-Sapphire technology has been successfully transferred to OKI's Hachioji, Japan fabrication facility. Several Peregrine products have now been fabricated with performance verified. The process qualification activity is currently underway, with completion expected by June 2004.

"Peregrine's yield and performance standards for UTSi are very high," stated Mark Miscione, vice president of Technology at Peregrine Semiconductor. "The speed at which OKI was able to accomplish this technology transfer and the performance of the resulting components have both been excellent," he added.

"OKI has confirmed the excellent RF performance and the maturity of Peregrine's UTSi SOS technology," commented Yoshiki Nagatomo, senior manager of Advanced Technology R&D at OKI Electric, who leads the OKI process transfer team. "Now, high performance UTSi RF CMOS products can be sourced from multiple suppliers, which is a great benefit to wireless designers incorporating high-performance RF components," he said.

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“We’re very pleased to have OKI as a strategic partner and second source,” said Jim Cable, president and CEO of Peregrine Semiconductor. “As we prepare the company for rapid shipment growth the additional manufacturing capability offered by OKI will be invaluable to Peregrine and its customers.”

About UTSi[®] CMOS Silicon-On-Sapphire (SOS) Technology

UTSi[®] CMOS is a proprietary, patented variation of silicon-on-insulator (SOI) technology. It is the first commercially qualified use of sapphire substrates with high yields and competitive costs. UTSi CMOS combines high-performance RF, mixed-signal, passive elements, nonvolatile memory and digital functions on a single device. Significant performance advantages exist over competing mixed-signal processes such as GaAs, SiGe BiCMOS and bulk silicon CMOS in applications where RF performance, low power and integration are paramount. Additionally, because UTSi SOS is fabricated in standard high-volume CMOS facilities, Peregrine products benefit from the fundamental cost effectiveness and high yields, scalability and integration of CMOS, while achieving the performance of SiGe and GaAs. And since sapphire is a near perfect insulator, UTSi SOS products can integrate high-quality passive devices directly into the IC, offering unprecedented levels of RF integration and cost effectiveness.

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About Peregrine Semiconductor

Peregrine Semiconductor Corporation designs, manufactures, and markets high-speed communications integrated circuits for the wireless, satellite and broadband cable communications markets. Using its patented Ultra-Thin-Silicon (UTSi™) CMOS process, Peregrine has developed a series of radio frequency IC products for high-growth applications, including CDMA and GSM digital cellular, and space and defense radiation hard ICs, and switching functions for video applications. Peregrine, headquartered in San Diego, California; maintains established design centers and operations in Chicago, IL; Aix-en-Provence, France; Sydney, Australia; and Tokyo, Japan. Additional information on Peregrine Semiconductor is available on its web site: www.peregrine-semi.com. Contact Peregrine's worldwide distribution partner, Richardson Electronics (NASDAQ: RELL), for sales information at 1-800-737-6937.

Peregrine Semiconductor is in no way affiliated with Peregrine Systems, a software company also based in San Diego, California.

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微波光电部专业代理经销高频、微波、光纤、光电元器件、组件、部件、模块、整机；电磁兼容元器件、材料、设备；微波 CAD、EDA 软件、开发测试仿真工具；微波、光纤仪器仪表。欢迎国外高科技微波、光纤厂商将优秀产品介绍到中国、共同开拓市场。长期大量现货专业批发高频、微波、卫星、光纤、电视、CATV 器件：晶振、VCO、连接器、PIN 开关、变容二极管、开关二极管、低噪晶体管、功率电阻及电容、放大器、功率管、MMIC、混频器、耦合器、功分器、振荡器、合成器、衰减器、滤波器、隔离器、环行器、移相器、调制解调器；光电子器件和组件：红外发射管、红外接收管、光电开关、光敏管、发光二极管和发光二极管组件、半导体激光二极管和激光器组件、光电探测器和光接收组件、光发射接收模块、光纤激光器和光放大器、光调制器、光开关、DWDM 用光发射和接收器件、用户接入系统光收发器件与模块、光纤连接器、光纤跳线/尾纤、光衰减器、光纤适配器、光隔离器、光耦合器、光环行器、光复用器/转换器；无线收发芯片和模组、蓝牙芯片和模组。

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传真：0755-83376182 (0) 13823648918 MSN: SUNS8888@hotmail.com

邮编：518033 E-mail:szss20@163.com QQ: 195847376

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西安分公司：西安高新开发区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL: 029-81022619 13072977981 FAX:029-88789382